



7N60-ML

Power MOSFET

7.0A, 600V N-CHANNEL POWER MOSFET

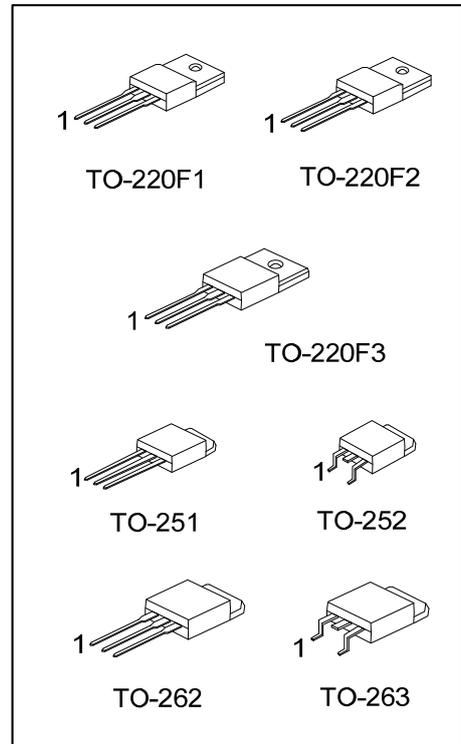
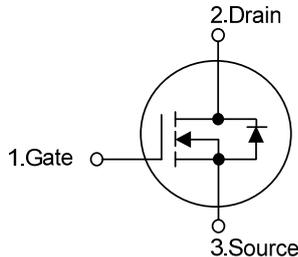
DESCRIPTION

The UTC **7N60-ML** is a high voltage power MOSFET designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and high rugged avalanche characteristics. This power MOSFET is usually used in high speed switching applications of switching power supplies and adaptors.

FEATURES

- * $R_{DS(ON)} \leq 1.2 \Omega @ V_{GS}=10V, I_D=3.5A$
- * Fast switching capability
- * Avalanche energy tested
- * Improved dv/dt capability, high ruggedness

SYMBOL



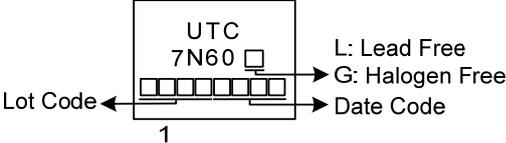
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
7N60L-TF1-T	7N60G-TF1-T	TO-220F1	G	D	S	Tube
7N60L-TF2-T	7N60G-TF2-T	TO-220F2	G	D	S	Tube
7N60L-TF3T-T	7N60G-TF3T-T	TO-220F3	G	D	S	Tube
7N60L-TM3-T	7N60G-TM3-T	TO-251	G	D	S	Tube
7N60L-TN3-R	7N60G-TN3-R	TO-252	G	D	S	Tape Reel
7N60L-T2Q-T	7N60G-T2Q-T	TO-262	G	D	S	Tube
7N60L-TQ2-T	7N60G-TQ2-T	TO-263	G	D	S	Tube
7N60L-TQ2-R	7N60G-TQ2-R	TO-263	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>7N60G-TF1-T</p>	<p>(1) T: Tube, R: Tape Reel (2) TF1: TO-220F1, TF2: TO-220F2, TF3T: TO-220F3 TM3: TO-251, TN3: TO-252, T2Q: TO-262, TQ2: TO-263 (3) G: Halogen Free and Lead Free, L: Lead Free</p>
--------------------	--

MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	600	V
Gate-Source Voltage		V_{GSS}	± 30	V
Continuous Drain Current		I_D	7	A
Pulsed Drain Current (Note 2)		I_{DM}	14	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	367	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.55	V/ns
Power Dissipation	TO-220F1/TO-220F2 TO-220F3	P_D	35	W
	TO-262/TO-263		100	W
	TO-251/TO-252		52	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. $L = 30\text{mH}$, $I_{AS} = 4.95\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 25\ \Omega$, Starting $T_J = 25^\circ\text{C}$

4. $I_{SD} \leq 7.0\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220F1/TO-220F2 TO-220F3/TO-262 TO-263	θ_{JA}	62.5	$^\circ\text{C}/\text{W}$	
	TO-251/TO-252		110	$^\circ\text{C}/\text{W}$	
	Junction to Case		TO-220F1/TO-220F2 TO-220F3	3.57	$^\circ\text{C}/\text{W}$
			TO-262/TO-263	1.25	$^\circ\text{C}/\text{W}$
TO-251/TO-252		2.4 (Note)	$^\circ\text{C}/\text{W}$		

Note: Device mounted on FR-4 substrate P_C board, 2oz copper, with 1inch square copper plate.

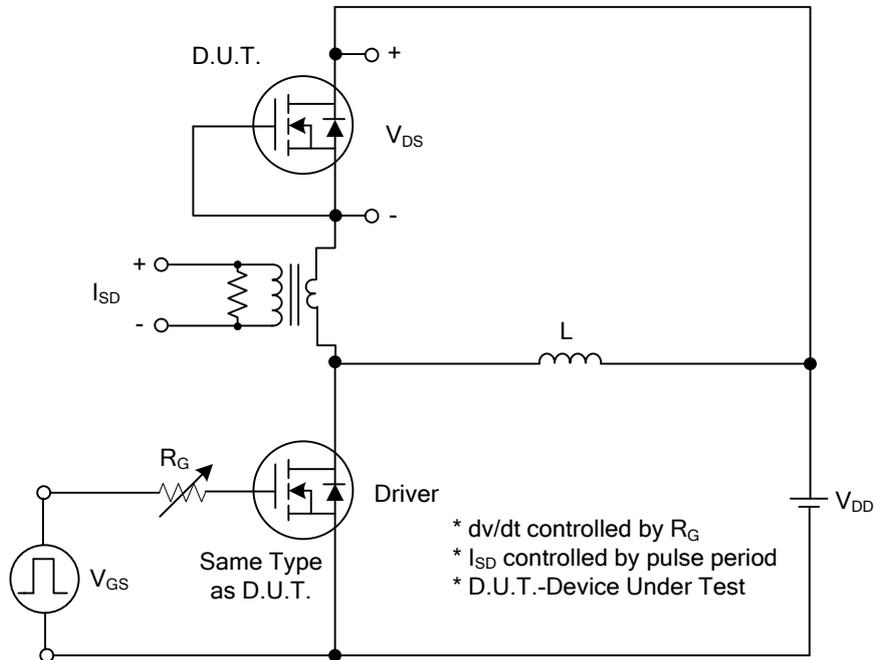
■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	600			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=600V, V_{GS}=0V$			10	μA
Gate- Source Leakage Current	Forward	$V_{GS}=30V, V_{DS}=0V$			100	nA
	Reverse		$V_{GS}=-30V, V_{DS}=0V$			-100
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=3.5A$			1.2	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{DS}=25V, V_{GS}=0V, f=1.0\text{MHz}$		915		pF
Output Capacitance	C_{OSS}			105		pF
Reverse Transfer Capacitance	C_{RSS}			12		pF
SWITCHING CHARACTERISTICS						
Total Gate Charge (Note 1)	Q_G	$V_{DS}=480V, V_{GS}=10V, I_D=7.0A$ $I_G=1\text{mA}$ (Note 1, 2)		24.5		nC
Gate-Source Charge	Q_{GS}			5.8		nC
Gate-Drain Charge	Q_{GD}			6.5		nC
Turn-On Delay Time (Note 1)	$t_{D(ON)}$	$V_{DS}=100V, V_{GS}=10V,$ $I_D=7.0A, R_G=25\Omega$ (Note 1, 2)		11		ns
Turn-On Rise Time	t_R			20.5		ns
Turn-Off Delay Time	$t_{D(OFF)}$			80		ns
Turn-Off Fall Time	t_F			32.3		ns
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
Maximum Body-Diode Continuous Current	I_S				7	A
Maximum Body-Diode Pulsed Current	I_{SM}				14	A
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	$I_S=7.0A, V_{GS}=0V$			1.4	V
Reverse Recovery Time (Note 1)	t_{rr}	$I_S=7.0A, V_{GS}=0V$ $di/dt=100A/\mu s$		290		ns
Reverse Recovery Charge	Q_{rr}				5.92	

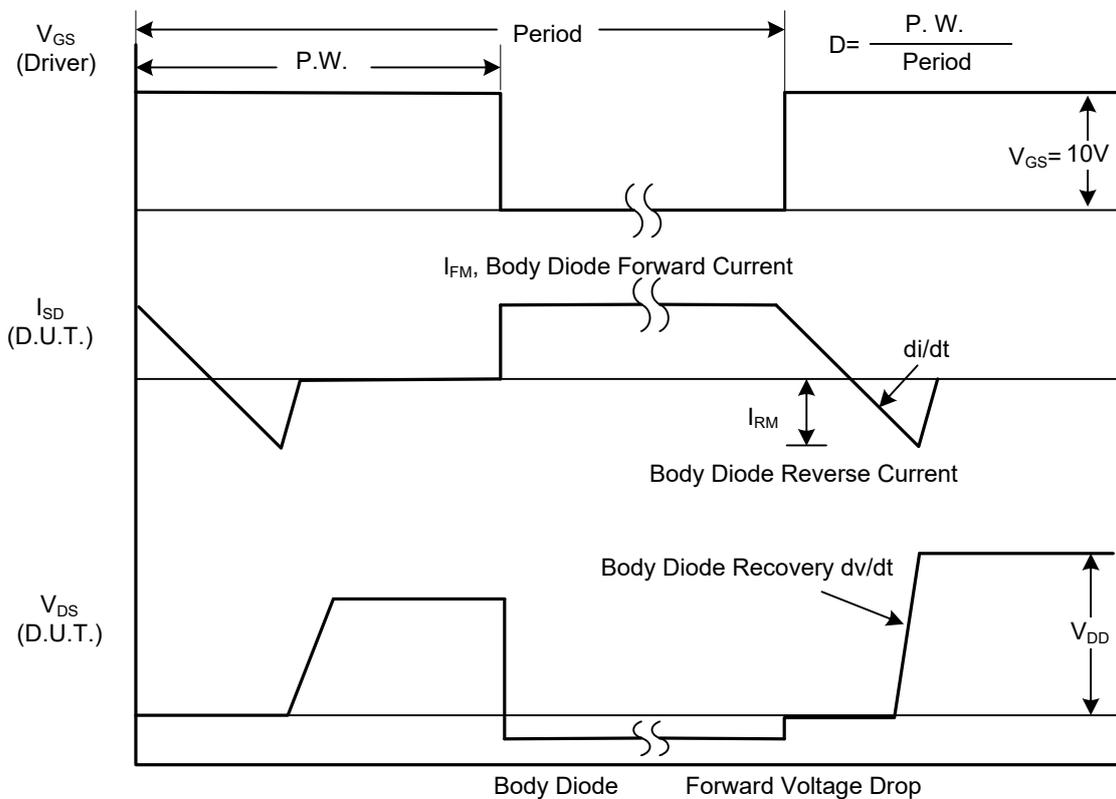
Notes: 1. Pulse Test: Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

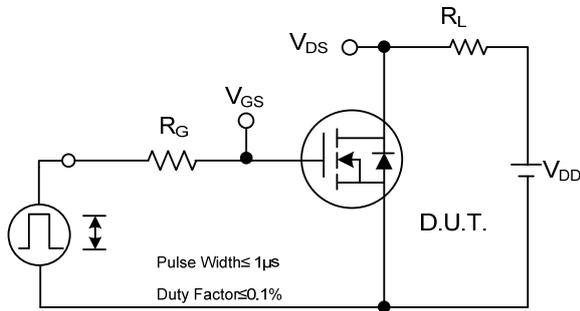


Peak Diode Recovery dv/dt Test Circuit

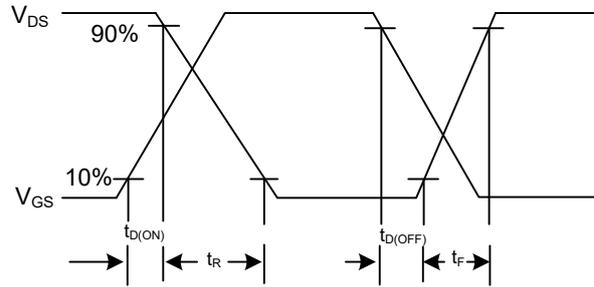


Peak Diode Recovery dv/dt Waveforms

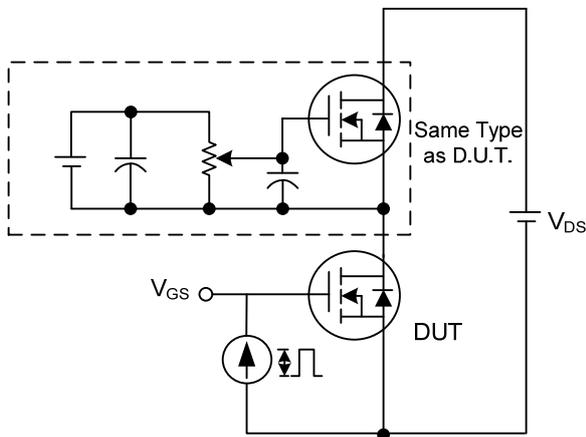
■ TEST CIRCUITS AND WAVEFORMS



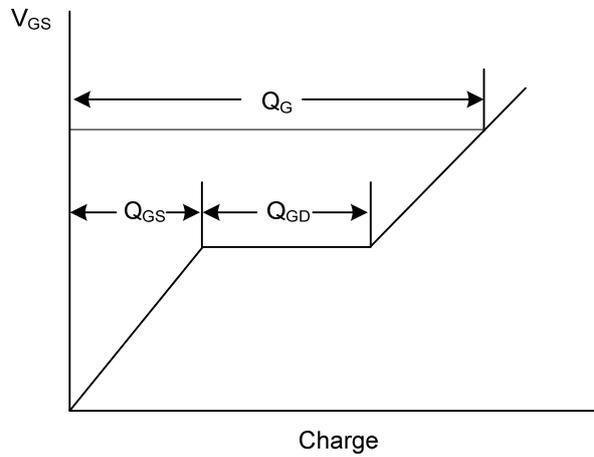
Switching Test Circuit



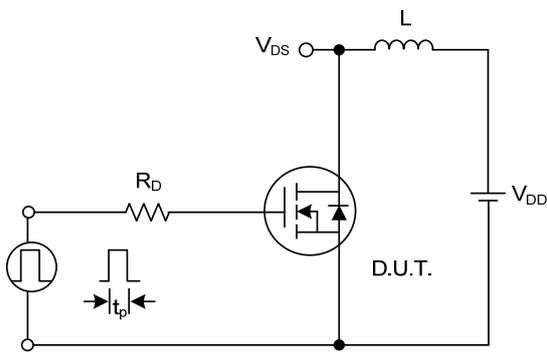
Switching Waveforms



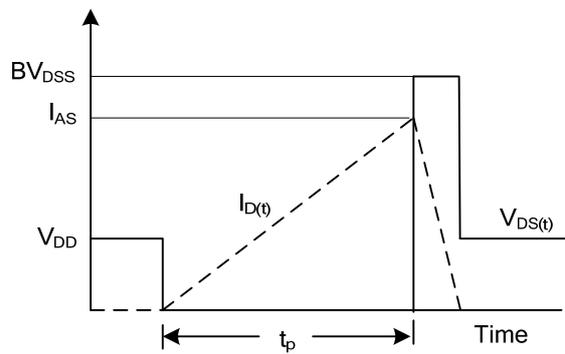
Gate Charge Test Circuit



Gate Charge Waveform

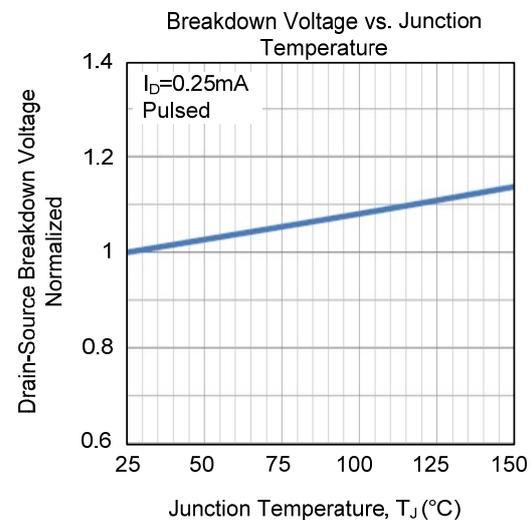
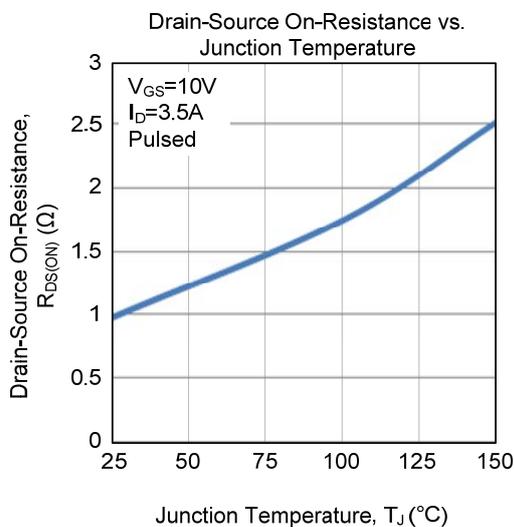
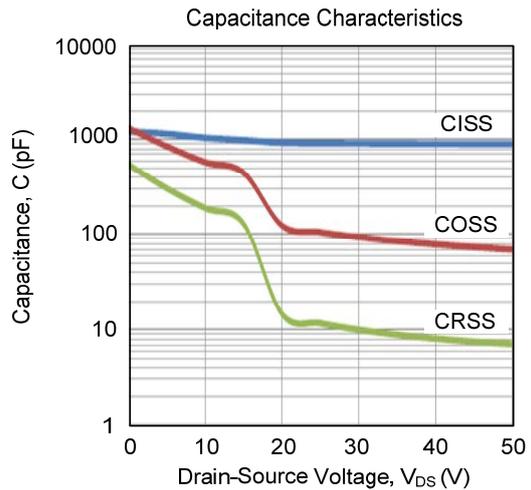
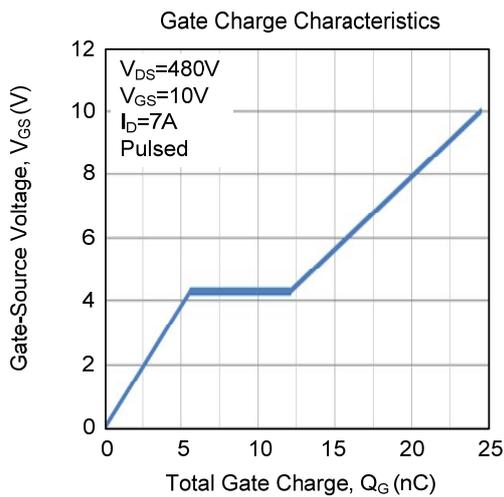
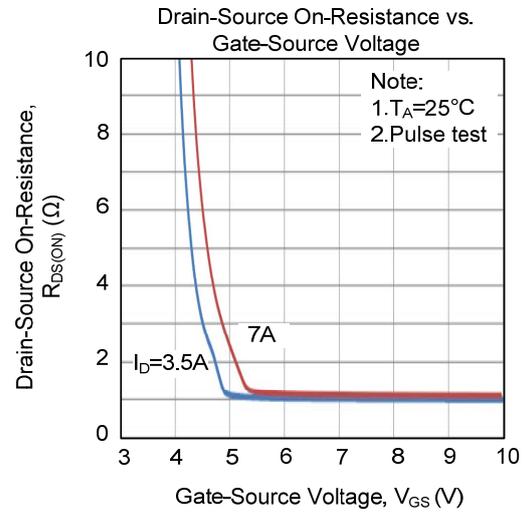
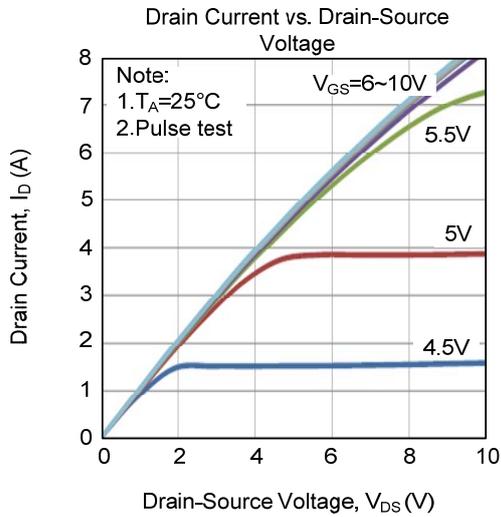


Unclamped Inductive Switching Test Circuit

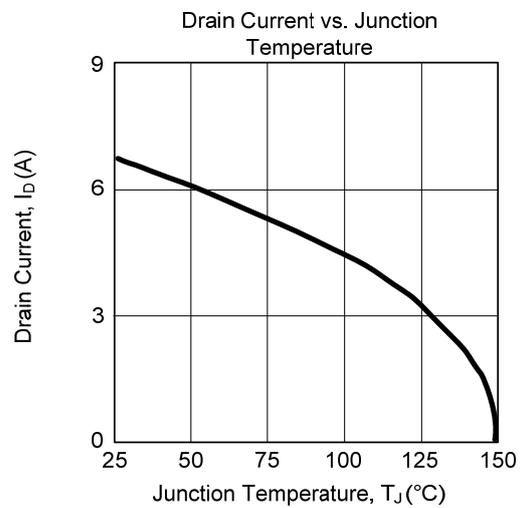
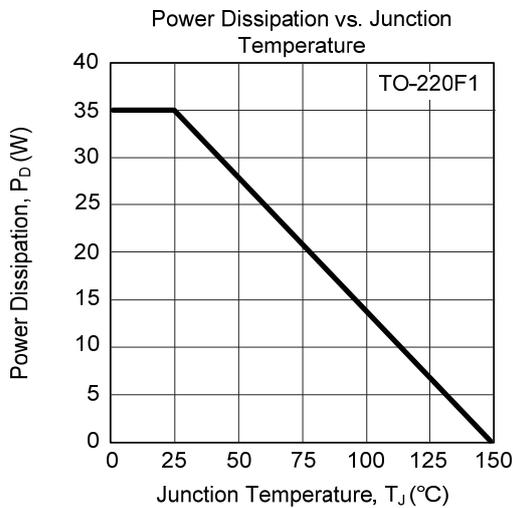
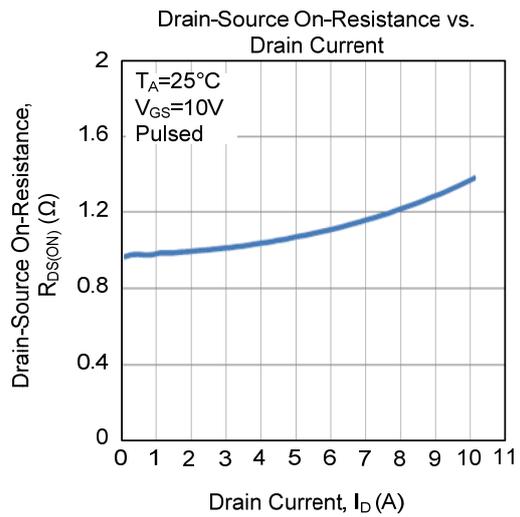
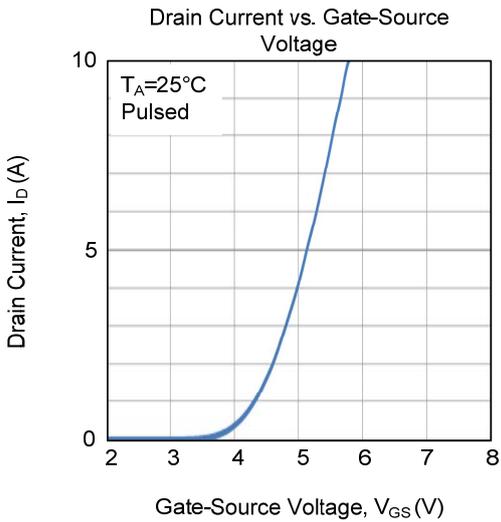
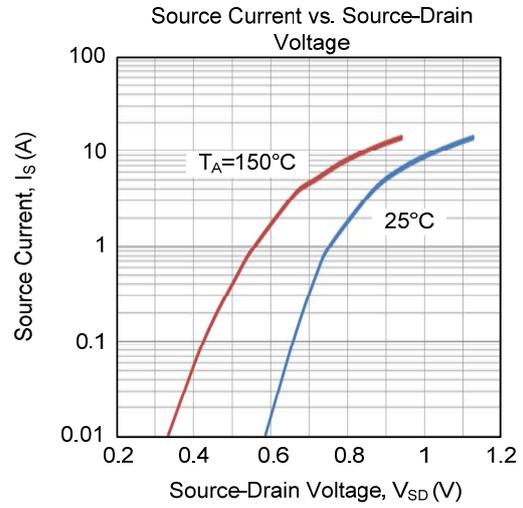
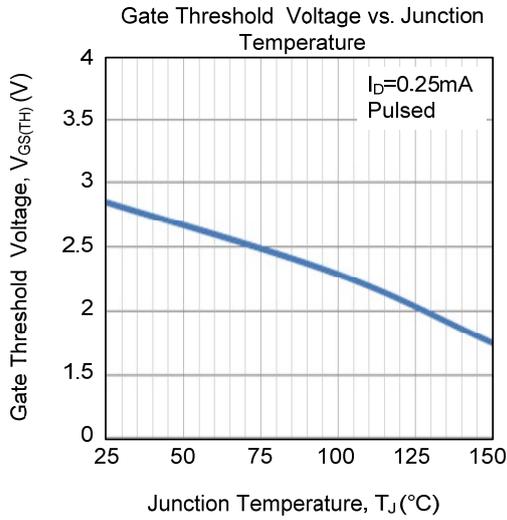


Unclamped Inductive Switching Waveforms

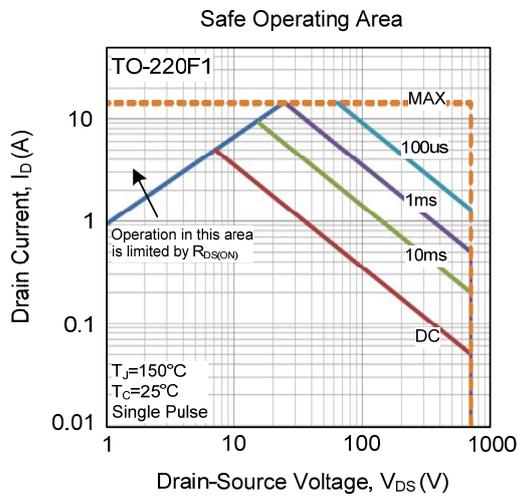
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.